

Power management (dual digital transistors)

EMC3 / UMC3N / FMC3A

●Features

- 1) Both the DTA114E chip and DTC114E chip in a EMT or UMT or SMT package.
- 2) Ideal for power switch circuits.
- 3) Mounting cost and area can be cut in half.

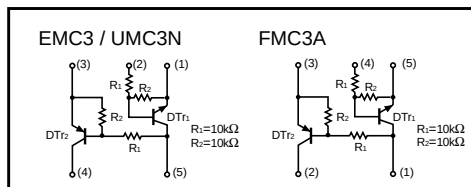
●Structure

Epitaxial planar type

NPN / PNP silicon transistor (Built-in resistor type.)

The following characteristics apply to both DTr₁ and DTr₂, however, the “-” sign on DTr₂ values for the PNP type have been omitted.

●Equivalent circuit

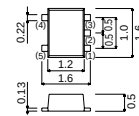


●Packaging specifications

Type	Package	Taping		
	Code	T2R	TR	T148
	Basic ordering unit (pieces)	8000	3000	3000
EMC3		○	—	—
UMC3N		—	○	—
FMC3A		—	—	○

●External dimensions (Units : mm)

EMC3

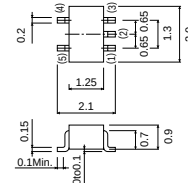


Each lead has same dimensions

ROHM : EMT5

Abbreviated symbol : C3

UMC3N



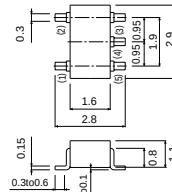
Each lead has same dimensions

ROHM : UMT5

EIAJ : SC-88A

Abbreviated symbol : C3

FMC3A



Each lead has same dimensions

ROHM : SMT5

EIAJ : SC-74A

Abbreviated symbol : C3

Transistors

●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Supply voltage		V _{CC}	50	V
Input voltage		V _{IN}	40	V
			-10	
Output current		I _O	50	mA
		I _{C (Max.)}	100	
Power dissipation	EMC3, UMC3N	P _d	150 (TOTAL)	mW
	FMC3A		300 (TOTAL)	
Junction temperature		T _j	150	°C
Storage temperature		T _{stg}	-55~+150	°C

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I (off)}	—	—	0.5	V	V _{CC} =5V, I _O =100μA
	V _{I (on)}	3	—	—		V _O =0.3V, I _O =10mA
Output voltage	V _{O (on)}	—	0.1	0.3	V	I _O =10mA, I _I =0.5mA
Input current	I _I	—	—	0.88	mA	V _I =5V
Output current	I _{O (off)}	—	—	0.5	μA	V _{CC} =50V, V _I =0V
DC current gain	G _I	30	—	—	—	V _O =5V, I _O =5mA
Transition frequency	f _T	—	250	—	MHz	V _{CE} =10mA, I _E =-5mA, f=100MHz
Input resistance	R _I	7	10	13	kΩ	—
Resistance ratio	R ₂ /R ₁	0.8	1	1.2	—	—

* Transition frequency of the device

●Electrical characteristic curves

DTr1 (NPN)

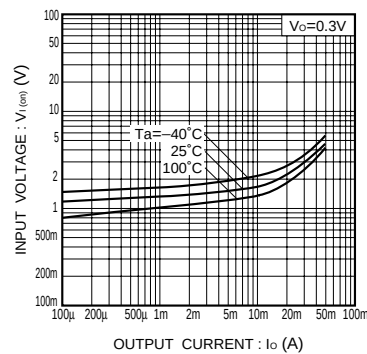


Fig.1 Input voltage vs. output current (ON characteristics)

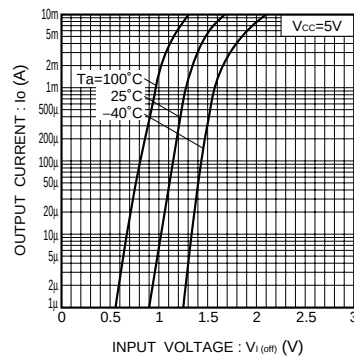


Fig.2 Output current vs. input voltage (OFF characteristics)

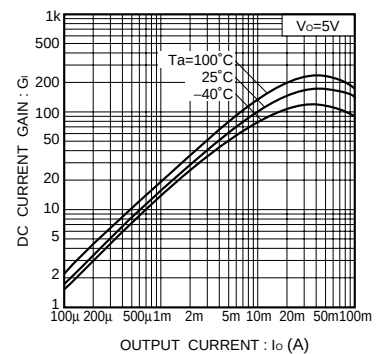


Fig.3 DC current gain vs. output current

Transistors

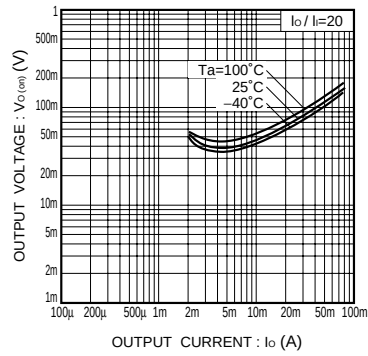


Fig.4 Output voltage vs. output current

DT₁₂ (PNP)

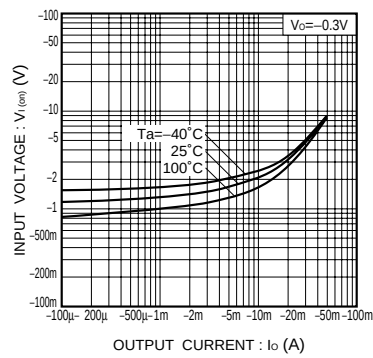


Fig.5 Input voltage vs. output current (ON characteristics)

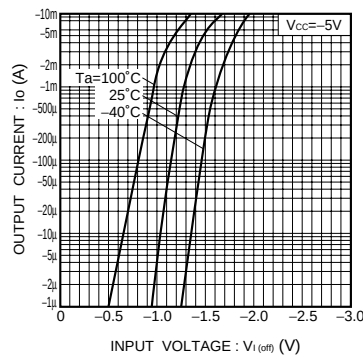


Fig.6 Output current vs. input voltage (OFF characteristics)

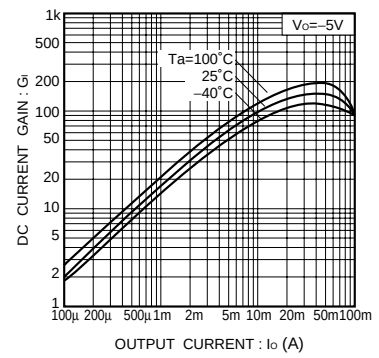


Fig.7 DC current gain vs. output current

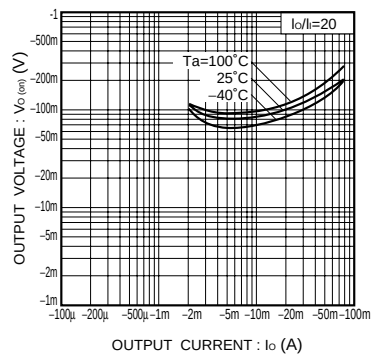


Fig.8 Output voltage vs. output current